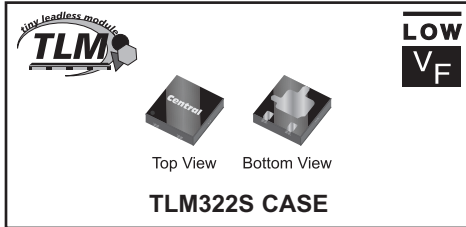


CTLSH1-40M322S

**SURFACE MOUNT  
HIGH CURRENT, LOW V<sub>F</sub>  
SILICON SCHOTTKY RECTIFIER**



www.centrasemi.com



**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CTLSH1-40M322S is a low V<sub>F</sub> Schottky rectifier designed for applications where small size and operational efficiency are prime requirements. With a maximum power dissipation of 1.45W, and a very small package footprint (approximately equal to the SOT-363), this Tiny Leadless Module (TLM) is capable of dissipating up to 4 times the power of similar devices in a comparable surface mount package.

**MARKING CODE: CBAS**

**APPLICATIONS:**

- DC-DC converters
- Reverse battery protection
- Battery powered devices including cell phones, PDAs, digital cameras, MP3 players, etc.

**FEATURES:**

- High forward current (I<sub>F</sub>=1.0A)
- Low forward voltage drop (V<sub>F</sub>=0.55V MAX @ 1.0A)
- High thermal efficiency

**MAXIMUM RATINGS:** (T<sub>A</sub>=25°C)

Peak Repetitive Reverse Voltage  
 Continuous Forward Current  
 Peak Repetitive Forward Current, tp≤1.0ms  
 Peak Forward Surge Current, tp=8.0ms  
 Power Dissipation (Note 1)  
 Operating and Storage Junction Temperature  
 Thermal Resistance (Note 1)

SYMBOL		UNITS
V <sub>RRM</sub>	40	V
I <sub>F</sub>	1.0	A
I <sub>FRM</sub>	3.5	A
I <sub>FSM</sub>	10	A
P <sub>D</sub>	1.45	W
T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
θ <sub>JA</sub>	86.2	°C/W

**ELECTRICAL CHARACTERISTICS:** (T<sub>A</sub>=25°C unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I <sub>R</sub>	V <sub>R</sub> =5.0V			10	μA
I <sub>R</sub>	V <sub>R</sub> =8.0V			20	μA
I <sub>R</sub>	V <sub>R</sub> =15V			50	μA
I <sub>R</sub>	V <sub>R</sub> =40V			0.2	mA
I <sub>R</sub>	V <sub>R</sub> =40V, T <sub>A</sub> =100°C			20	mA
BV <sub>R</sub>	I <sub>R</sub> =100μA	40			V
V <sub>F</sub>	I <sub>F</sub> =10mA			0.29	V
V <sub>F</sub>	I <sub>F</sub> =100mA			0.36	V
V <sub>F</sub>	I <sub>F</sub> =500mA			0.45	V
V <sub>F</sub>	I <sub>F</sub> =1.0A			0.55	V
C <sub>J</sub>	V <sub>R</sub> =4.0V, f=1.0MHz		50		pF
t <sub>rr</sub>	I <sub>F</sub> =I <sub>R</sub> =500mA, I <sub>rr</sub> =50mA, R <sub>L</sub> =50Ω		15		ns

Notes: (1) FR-4 Epoxy PC Board with copper mounting pad area of 21mm<sup>2</sup>.

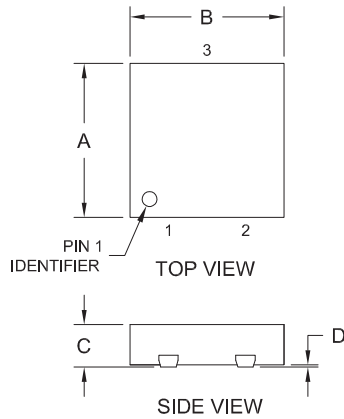
R0 (27-September 2012)

CTLSH1-40M322S

**SURFACE MOUNT  
HIGH CURRENT, LOW  $V_F$   
SILICON SCHOTTKY RECTIFIER**

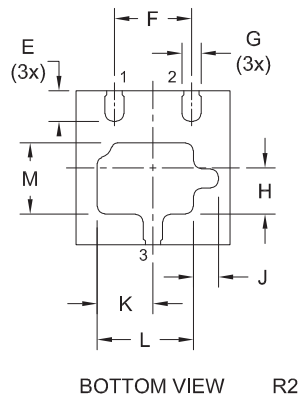


**TLM322S CASE - MECHANICAL OUTLINE**

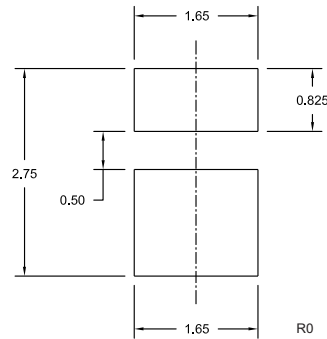


SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.076	0.081	1.95	2.05
B	0.076	0.081	1.95	2.05
C	0.019	0.024	0.50	0.60
D	0.000	0.002	0.00	0.05
E	0.011	0.020	0.30	0.50
F	0.039		1.00	
G	0.007	0.012	0.18	0.30
H	0.017	0.028	0.45	0.70
J	0.008	0.017	0.22	0.43
K	0.024	0.033	0.62	0.83
L	0.043	0.054	1.10	1.35
M	0.030	0.041	0.77	1.03

TLM322S (REV:R2)

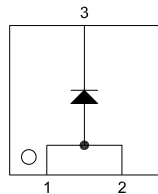


**SUGGESTED MOUNTING PADS  
For Maximum Power Dissipation  
(Dimensions in mm)**



For standard mounting refer to TLM322S Package Details

**PIN CONFIGURATION**



**LEAD CODE:**

- 1) Anode
- 2) Anode
- 3) Cathode

**MARKING CODE: CBAS**

R0 (27-September 2012)